

CDBDSC3650-G

Reverse Voltage: 650 V

Forward Current: 3 A

RoHS Device



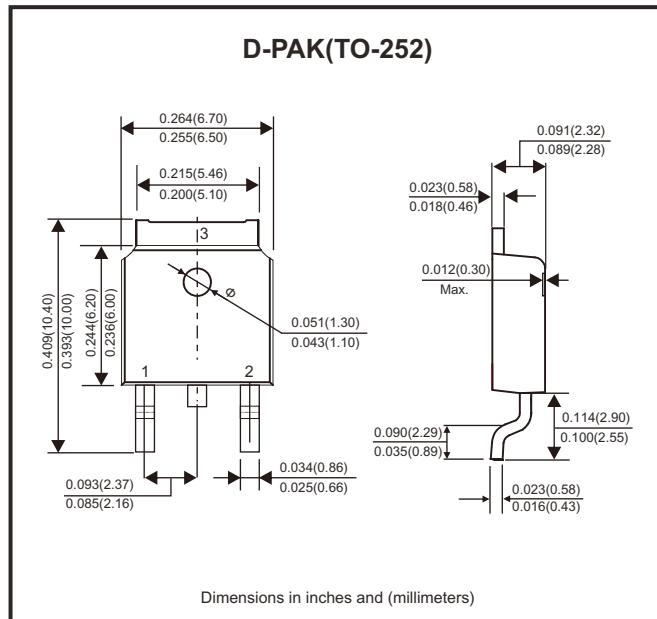
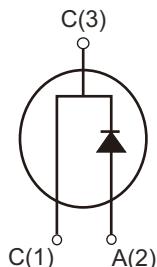
Features

- Rated to 650V at 3 Amps
- Short recovery time.
- High speed switching possible.
- High frequency operation.
- High temperature operation.
- Temperature independent switching behaviour.
- Positive temperature coefficient on VF.

Mechanical data

- Case: TO-252/DPAK, molded plastic.
- Terminals: Solderable per MIL-STD-750, method 2026.

Circuit Diagram



Maximum Ratings (at TA=25°C, unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Repetitive peak reverse voltage		V _{RRM}	650	V
Surge peak reverse voltage		V _{RSM}	650	V
DC blocking voltage		V _{DC}	650	V
Typical continuous forward current	T _c = 150°C	I _F	3	A
Repetitive peak forward surge current	T _c = 25°C, tp = 10ms Half sine wave, D = 0.3	I _{FRM}	15	A
Non-repetitive peak forward surge current	T _c = 25°C, tp = 10ms Half sine wave	I _{FSM}	30	A
Power dissipation	T _c = 25°C	P _{TOT}	53.2	W
	T _c = 110°C		23	
Typical thermal resistance	Junction to case	R _{θJC}	2.82	°C/W
Operating junction temperature range		T _J	-55 ~ +175	°C
Storage temperature range		T _{STG}	-55 ~ +175	°C

Silicon Carbide Power Schottky Diode

Comchip
SMD Diode Specialist

Electrical Characteristics (at $T_A=25^\circ\text{C}$, unless otherwise noted)

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 3\text{A}, T_J = 25^\circ\text{C}$	V_F		1.4	1.7	V
	$I_F = 3\text{A}, T_J = 175^\circ\text{C}$			1.8		
Reverse current	$V_R = 650\text{V}, T_J = 25^\circ\text{C}$	I_R		10	100	μA
	$V_R = 650\text{V}, T_J = 175^\circ\text{C}$			20		
Total capacitive charge	$V_R = 400\text{V}, T_J = 150^\circ\text{C}$ $Q_c = \int_0^{V_R} C(V) dV$	Q_c		11		nC
Total capacitance	$V_R = 0\text{V}, T_J = 25^\circ\text{C}, f = 1\text{MHz}$	C		190		pF
	$V_R = 200\text{V}, T_J = 25^\circ\text{C}, f = 1\text{MHz}$			23		

Rating and Characteristics Curves (CDBDSC3650-G)

Fig.1 - Forward Characteristics

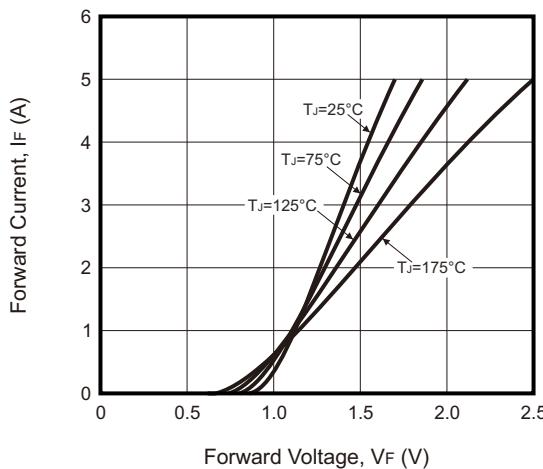


Fig.2 - Reverse Characteristics

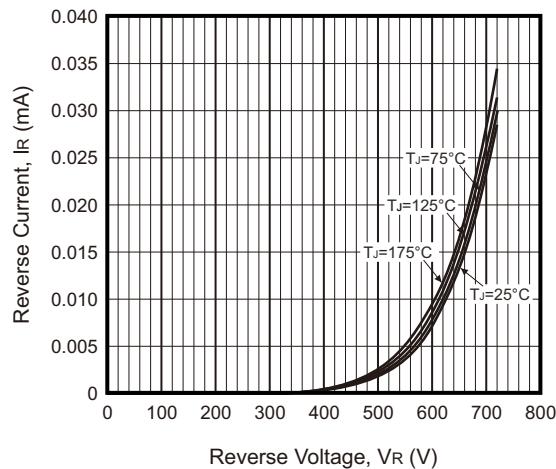


Fig.3 - Current Derating

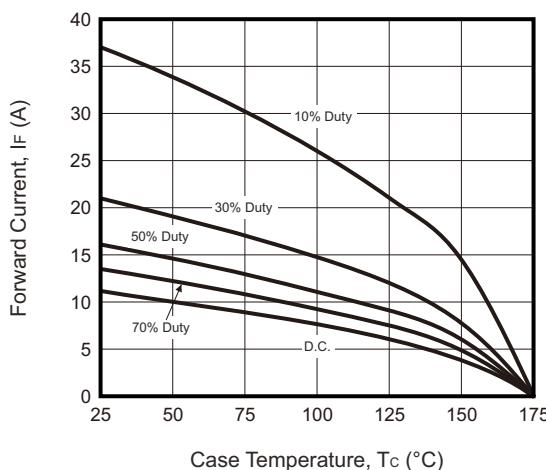
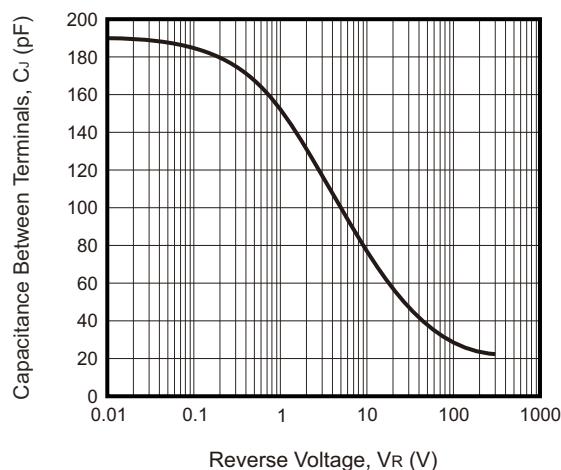


Fig.4 - Capacitance vs. Reverse Voltage

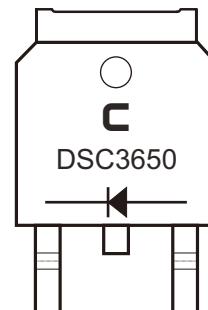


Company reserves the right to improve product design , functions and reliability without notice.

REV:A

Marking Code

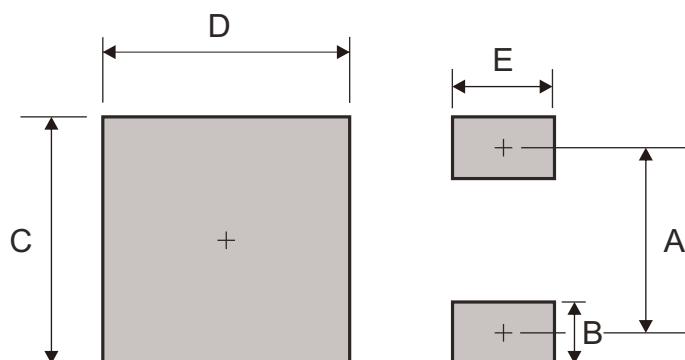
Part Number	Marking Code
CBDSC3650-G	DSC3650



C = Comchip Logo

Suggested PAD Layout

SIZE	TO-252 / DPAK	
	(mm)	(inch)
A	4.57	0.180
B	1.20	0.047
C	5.80	0.228
D	5.85	0.230
E	2.00	0.079



Standard Packaging

Case Type	TUBE PACK	
	TUBE (pcs)	BOX (pcs)
TO-252/D-PAK	80	1,600